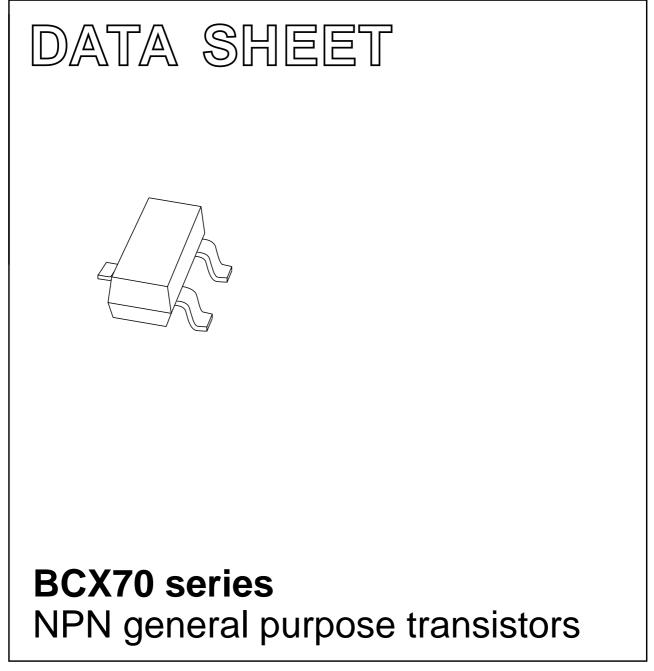
DISCRETE SEMICONDUCTORS



Product specification Supersedes data of 1999 Apr 15 2004 Jan 16



FEATURES

- Low current (max. 100 mA)
- Low voltage (max. 45 V).

APPLICATIONS

• General purpose switching and amplification.

DESCRIPTION

NPN transistor in a SOT23 plastic package. PNP complements: BCX71 series.

MARKING

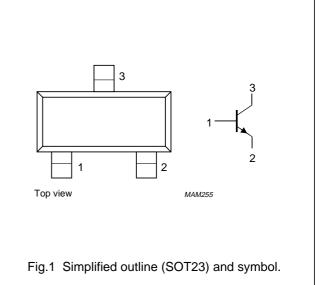
TYPE NUMBER	MARKING CODE ⁽¹⁾
BCX70G	AG*
BCX70H	AH*
BCX70J	AJ*
BCX70K	AK*

Note

- 1. * = p : Made in Hong Kong.
 - * = t : Made in Malaysia.
 - * = W : Made in China.

ORDERING INFORMATION

PIN	DESCRIPTION	
1	base	
2	emitter	
3	collector	



TYPE		PACKAGE		
NUMBER NAME		DESCRIPTION	VERSION	
BCX70G	-	plastic surface mounted package; 3 leads	SOT23	
BCX70H				
BCX70J				
BCX70K	1			

BCX70 series

BCX70 series

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS		MAX.	UNIT
V _{CBO}	collector-base voltage	open emitter	-	45	V
V _{CEO}	collector-emitter voltage	open base	-	45	V
V _{EBO}	emitter-base voltage	open collector	-	5	V
I _C	collector current (DC)		-	100	mA
I _{CM}	peak collector current		-	200	mA
I _{BM}	peak base current		-	200	mA
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	-	250	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	150	°C
T _{amb}	operating ambient temperature		-65	+150	°C

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	note 1	500	K/W

Note

1. Transistor mounted on an FR4 printed-circuit board.

BCX70 series

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
I _{CBO}	collector cut-off current	I _E = 0; V _{CB} = 45 V	-	_	20	nA
		$I_E = 0; V_{CB} = 45 V; T_{amb} = 150 °C$	_	_	20	μA
I _{EBO}	emitter cut-off current	$I_{C} = 0; V_{EB} = 4 V$	-	-	20	nA
h _{FE}	DC current gain	$I_{C} = 10 \ \mu A; V_{CE} = 5 \ V$				
	BCX70G		_	_	_	
	BCX70H		40	_	_	
	BCX70J		30	_	_	
	BCX70K		100	_	_	
	DC current gain	I _C = 2 mA; V _{CE} = 5 V				
	BCX70G		120	_	220	
	BCX70H		180	_	310	
	BCX70J		250	_	460	
	BCX70K		380	_	630	
	DC current gain	I _C = 50 mA; V _{CE} = 1 V				
	BCX70G		50	_	_	
	BCX70H		70	_	_	
	BCX70J		90	_	_	
	BCX70K		100	_	_	
V _{CEsat}	collector-emitter saturation voltage	I _C = 10 mA; I _B = 0.25 mA	50	_	350	mV
		I _C = 50 mA; I _B = 1.25 mA	100	_	550	mV
V _{BEsat}	base-emitter saturation voltage	I _C = 10 mA; I _B = 0.25 mA	600	_	850	mV
		I _C = 50 mA; I _B = 1.25 mA	700	_	1050	mV
V _{BE}	base-emitter voltage	$I_{C} = 10 \ \mu\text{A}; \ V_{CE} = 5 \ V$	_	520	_	mV
		I _C = 2 mA; V _{CE} = 5 V	550	650	750	mV
		I _C = 50 mA; V _{CE} = 1 V	_	780	_	mV
C _c	collector capacitance	I _E = i _e = 0; V _{CB} = 10 V; f = 1 MHz	_	1.7	_	pF
C _e	emitter capacitance	$I_{C} = i_{c} = 0; V_{EB} = 0.5 V; f = 1 MHz$	-	11	-	pF
f _T	transition frequency	$I_{C} = 10 \text{ mA}; V_{CE} = 5 \text{ V}; f = 100 \text{ MHz};$ note 1	100	250	-	MHz
F	noise figure	$ I_{C} = 200 \ \mu\text{A}; \ V_{CE} = 5 \ \text{V}; \ \text{R}_{S} = 2 \ \text{k}\Omega; \\ f = 1 \ \text{kHz}; \ \text{B} = 200 \ \text{Hz} $	-	2	6	dB

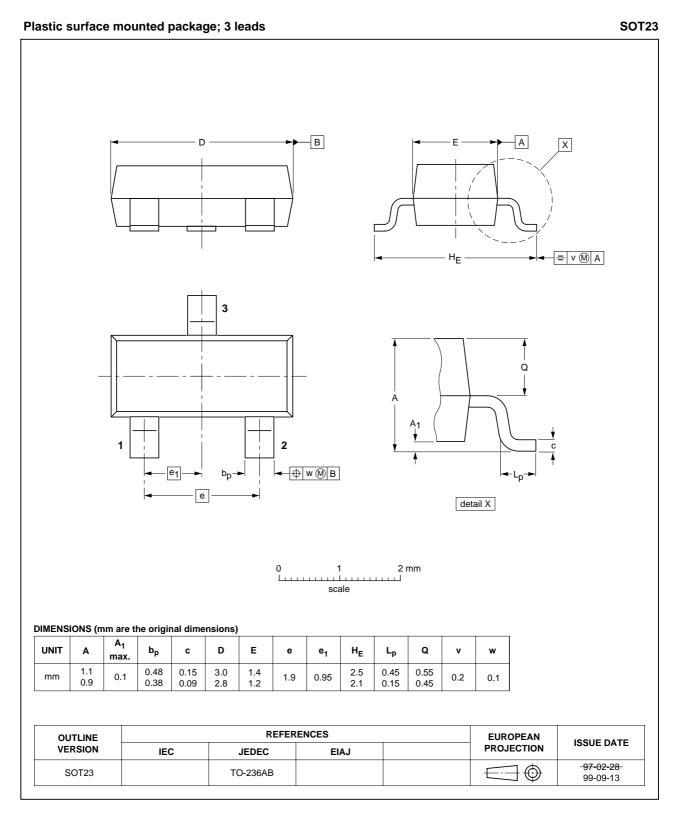
Note

1. Pulse test: $t_p \leq 300 \ \mu s; \ \delta \leq 0.02.$

BCX70 series

NPN general purpose transistors

PACKAGE OUTLINE



2004 Jan 16

BCX70 series

DATA SHEET STATUS

LEVEL	DATA SHEET STATUS ⁽¹⁾	PRODUCT STATUS ⁽²⁾⁽³⁾	DEFINITION
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
11	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

Notes

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.
- 3. For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

DEFINITIONS

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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